

Toshiba Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

# TPD1030F

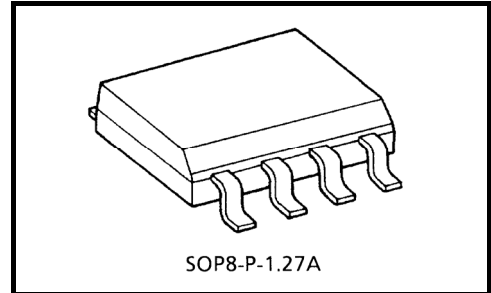
## 2-IN-1 Low-Side Switch for Motor, Solenoid and Lamp Drive

The TPD1030F is a 2-IN-1 low-side switch.

The IC has a vertical MOSFET output which can be directly driven from a CMOS or TTL logic circuit (e.g., an MPU). The IC is equipped with intelligent self-protection functions.

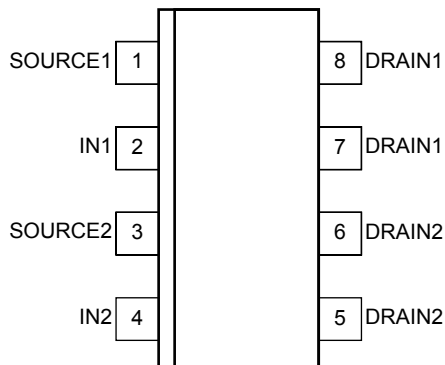
### Features

- Two built-in power IC chips with a new structure combining a control block and a vertical power MOSFET ( $L^2$ - $\pi$ -MOS) on each chip.
- Can directly drive a power load from a CMOS or TTL logic.
- Built-in protection circuits against overvoltage (active clamp), overtemperature (thermal shutdown), and overcurrent (current limiter).
- Low Drain-Source ON-resistance:  $R_{DS(ON)} = 0.6 \Omega$  (max) (@ $V_{IN} = 5 \text{ V}$ ,  $I_D = 0.5 \text{ A}$ ,  $T_{ch} = 25^\circ\text{C}$ )
- Low Leakage Current:  $I_{DSS} = 10 \mu\text{A}$  (max) (@ $V_{IN} = 0 \text{ V}$ ,  $V_{DS} = 30 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$ )
- Low Input Current:  $I_{IN} = 300 \mu\text{A}$  (max) (@ $V_{IN} = 5 \text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$ )
- 8-pin SOP package with embossed-tape packaging.

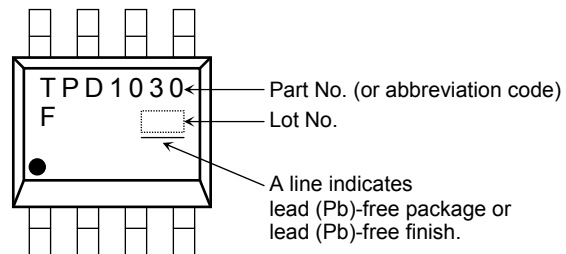


Weight: 0.08 g (typ.)

### Pin Assignment (top view)

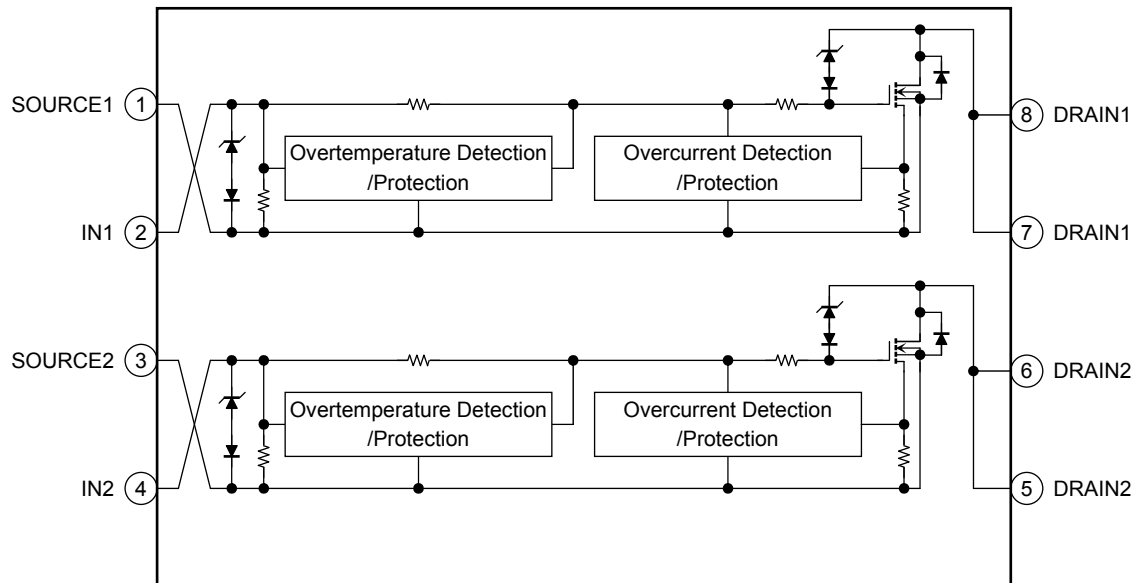


### Marking



Note1: Due to its MOS structure, this product is sensitive to static electricity.

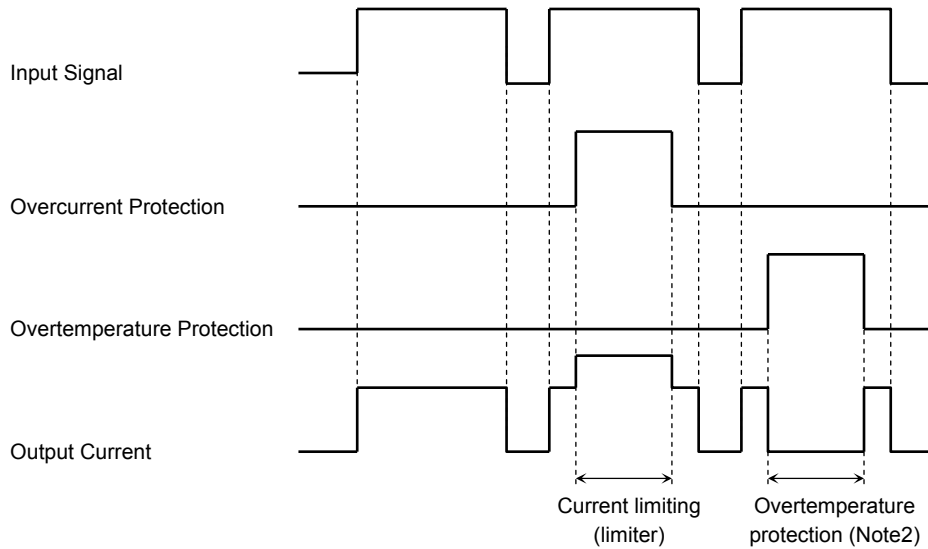
**Block Diagram**



**Pin Description**

| Pin No. | Symbol  | Pin Description   |
|---------|---------|---|
| 1       | SOURCE1 | Source pin 1  |
| 2       | IN1     | Input pin 1<br>This pin is connected to a pull-down resistor internally, so that even when input wiring is open-circuited, output can never be turned on inadvertently. |
| 3       | SOURCE2 | Source pin 2  |
| 4       | IN2     | Input pin 2<br>This pin is connected to a pull-down resistor internally, so that even when input wiring is open-circuited, output can never be turned on inadvertently. |
| 5, 6    | DRAIN2  | Drain pin 2<br>Drain current is limited (by current limiter) if it exceeds 1 A (min) in order to protect the IC.  |
| 7, 8    | DRAIN1  | Drain pin 1<br>Drain current is limited (by current limiter) if it exceeds 1 A (min) in order to protect the IC.  |

## Timing Chart



Note2: The overheating detector circuits feature hysteresis. After overheating is detected, normal operation is restored only when the channel temperature falls by the hysteresis amount (5°C typ.) in relation to the overheating detection temperature.

## Truth Table

| IN | V <sub>OUT</sub> | Mode            |
|----|------------------|-----------------|
| L  | H                | Normal          |
| H  | L                |                 |
| L  | H                | Overcurrent     |
| H  | H                |                 |
| L  | H                | Overtemperature |
| H  | H                |                 |

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics                               | Symbol               | Rating             | Unit |
|---|----------------------|--------------------|------|
| Drain-source voltage                          | V <sub>DS</sub> (DC) | 40                 | V    |
| Drain current                                 | I <sub>D</sub>       | Internally Limited | A    |
| Input voltage                                 | V <sub>IN</sub>      | -0.3 to 7          | V    |
| Power dissipation (t = 10 s)                  | P <sub>D</sub>       | 2.0<br>(Note 3)    | W    |
| Single pulse active clamp capability (Note 4) | E <sub>AS</sub>      | 10                 | mJ   |
| Active clamp current                          | I <sub>AR</sub>      | 1                  | A    |
| Repetitive active clamp capability (Note 5)   | E <sub>AR</sub>      | 0.2                | mJ   |
| Operating temperature                         | T <sub>opr</sub>     | -40 to 110         | °C   |
| Channel temperature                           | T <sub>ch</sub>      | 150                | °C   |
| Storage temperature                           | T <sub>stg</sub>     | -55 to 150         | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Thermal Characteristics

| Characteristics  | Symbol          | Max  | Unit |
|--|-----------------|------|------|
| Thermal resistance, channel to ambient (t = 10 s)<br>(Note3) | $R_{th} (ch-a)$ | 62.5 | °C/W |

Note 3: Drive operation: Mounted on glass epoxy board [25.4mm × 25.4mm × 0.8mm] (with the two devices operating)

Note 4: Active clamp capability (single pulse) test condition  
 $V_{DD} = 25 V$ , Starting  $T_{ch} = 25^{\circ}C$ ,  $L = 10 mH$ ,  $I_{AR} = 1 A$ ,  $R_G = 25 \Omega$

Note 5: Repetitive rating, pulse width limited by maximum channel temperature.

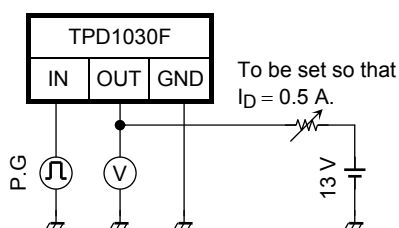
## Electrical Characteristics

| Characteristics                                  | Symbol                           | Test Circuit | Test Condition   | Min | Typ. | Max | Unit     |
|--|----------------------------------|--------------|--|-----|------|-----|----------|
| Drain-source clamp voltage                       | $V_{(CL) DSS}$                   | —            | $T_{ch} = -40 \sim 110^{\circ}C$<br>$V_{IN} = 0 V$ ,<br>$I_D = 1 mA$ | 40  | —    | 60  | V        |
| Input threshold voltage                          | $V_{th}$                         | —            | $T_{ch} = 25^{\circ}C$   | 1.0 | —    | 2.8 | V        |
|  |                                  |              | $T_{ch} = -40 \sim 110^{\circ}C$                                     |     |      |     |          |
| Protective circuit operation input voltage range | $V_{IN (opr)}$                   | —            | $T_{ch} = 25^{\circ}C$   | 3   | —    | 7   | V        |
|  |                                  |              | $T_{ch} = -40 \sim 110^{\circ}C$                                     | 3.5 | —    | 7   |          |
| Drain cut-off current                            | $I_{DSS}$                        | —            | $T_{ch} = 25^{\circ}C$   | —   | —    | 10  | $\mu A$  |
|  |                                  |              | $T_{ch} = -40 \sim 110^{\circ}C$                                     |     |      | 100 |          |
| Input current                                    | $I_{IN (1)}$                     | —            | $T_{ch} = 25^{\circ}C$   | —   | —    | 300 | $\mu A$  |
|  | $I_{IN (2)}$                     | —            | $T_{ch} = -40 \sim 110^{\circ}C$                                     | —   | —    | 350 |          |
| Drain-source on resistance                       | $R_{DS (ON)}$                    | —            | $T_{ch} = 25^{\circ}C$   | —   | 0.44 | 0.6 | $\Omega$ |
|  |                                  |              | $T_{ch} = -40 \sim 110^{\circ}C$                                     | —   | —    | 0.9 |          |
| Overtemperature protection                       | $T_S$                            | —            | —  | 150 | 160  | —   | °C       |
| Overcurrent protection                           | $I_S$                            | —            | $T_{ch} = 25^{\circ}C$   | 1   | 1.8  | —   | A        |
|  |                                  |              | $T_{ch} = -40 \sim 110^{\circ}C$                                     | 0.7 | —    | —   |          |
| Switching time                                   | $t_{ON}$                         | 1            | $T_{ch} = 25^{\circ}C$   | —   | —    | 30  | $\mu s$  |
|  |                                  |              | $T_{ch} = -40 \sim 110^{\circ}C$                                     |     |      | 60  |          |
|  | $T_{ch} = 25^{\circ}C$           |              | 60   |     |      |     |          |
|  | $T_{ch} = -40 \sim 110^{\circ}C$ |              | 90   |     |      |     |          |
| Source-drain diode forward voltage               | $V_{DSF}$                        | —            | $T_{ch} = 25^{\circ}C$   | —   | —    | 1.7 | V        |

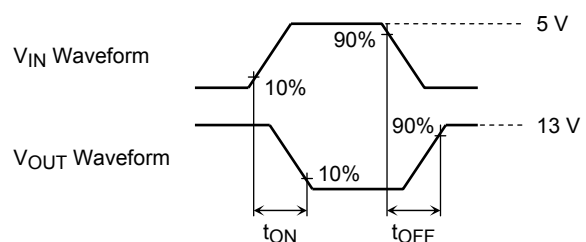
## Test Circuit 1

Switching time measuring circuit

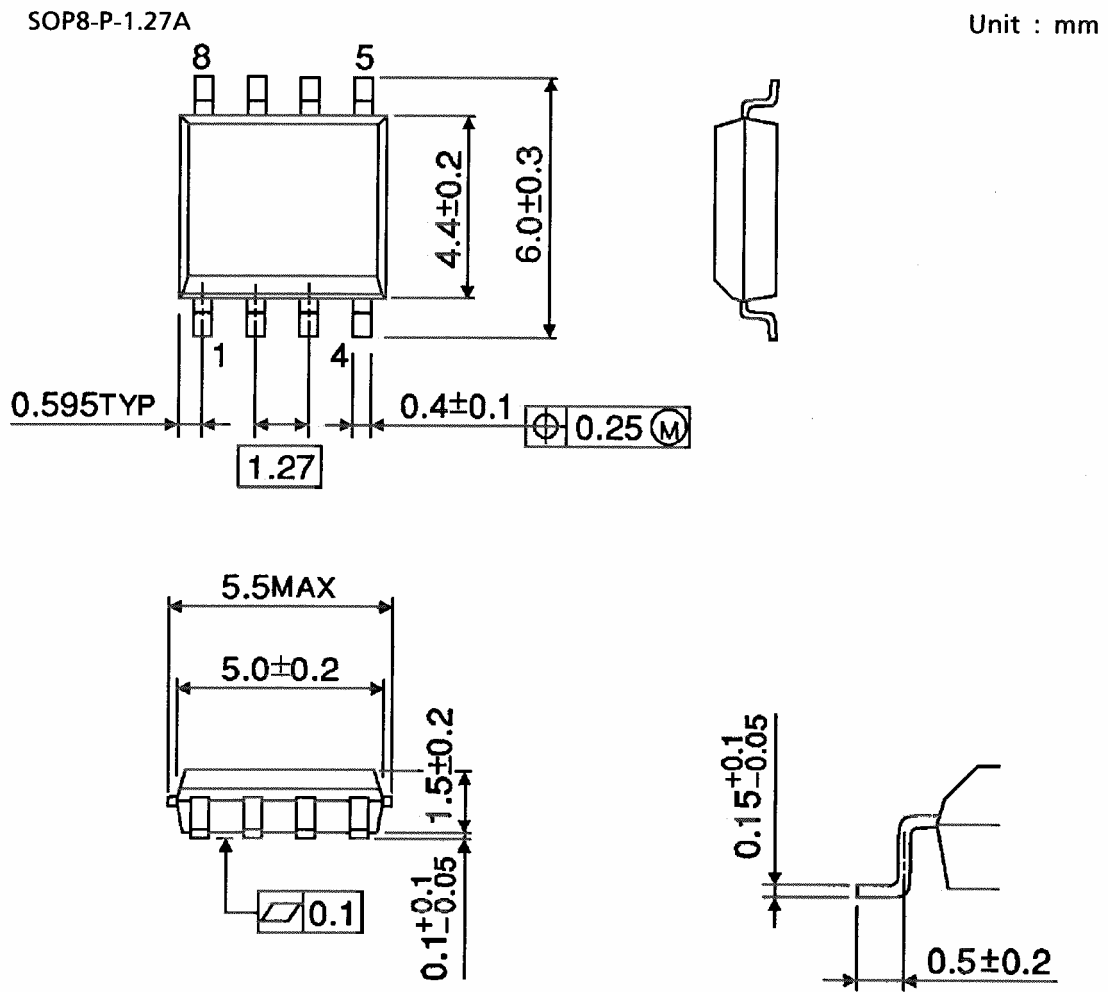
### Test Circuit



### Measured Waveforms



## Package Dimensions



Weight: 0.08 g (typ.)

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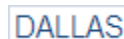
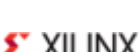
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